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ON Semiconductor®

February 2018

# FFPF20UA60DN

## 20 A, 600 V, Ultrafast II Dual Diode

### Features

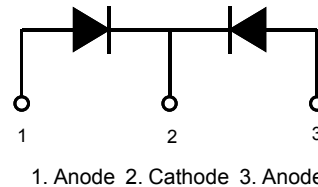
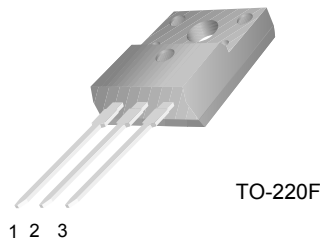
- Ultrafast Recovery  $t_{rr} = 120 \text{ ns}$  (@  $I_F = 10 \text{ A}$ )
- Max Forward Voltage,  $V_F = 2.3 \text{ V}$  (@  $T_C = 25^\circ\text{C}$ )
- 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- RoHS Compliant

### Description

The FFPF20UA60DN is an ultrafast II dual diode with low forward voltage drop and rugged UIS capability. This device is intended for use as freewheeling and clamping diodes in a variety of switching power supplies and other power switching applications. It is specially suited for use in switching power supplies and industrial applications as welder and UPS application.

### Applications

- Boost Diode in PFC and SMPS



### Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Rating	Unit
$V_{RRM}$	Peak Repetitive Reverse Voltage	600	V
$V_{RWM}$	Working Peak Reverse Voltage	600	V
$V_R$	DC Blocking Voltage	600	V
$I_{F(AV)}$	Average Rectified Forward Current @ $T_C = 25^\circ\text{C}$	10	A
$I_{FSM}$	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	50	A
$T_J, T_{STG}$	Operating and Storage Temperature Range	-65 to +175	$^\circ\text{C}$

### Thermal Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Max.	Unit
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	6.3	$^\circ\text{C}/\text{W}$

### Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFPF20UA60DN	FFPF20UA60DN	TO-220F	Tube	N/A	N/A	50

FFPF20UA60DN — Ultrafast II Dual Diode

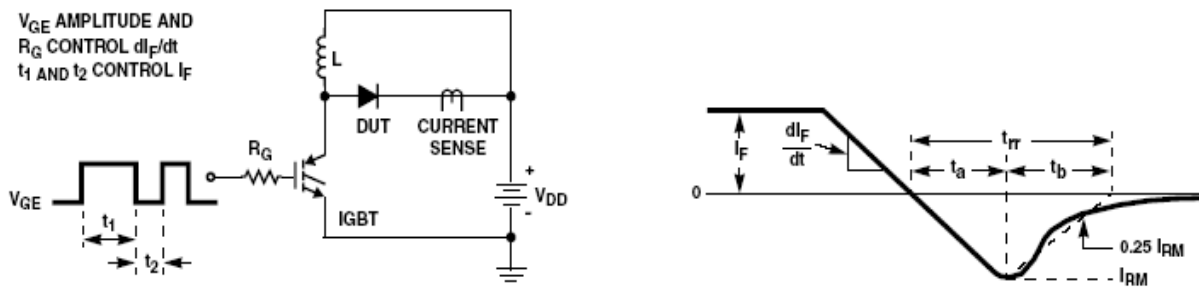
### Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Min.	Typ.	Max.	Unit
$V_{FM1}$	$I_F = 10\text{ A}$ $I_F = 10\text{ A}$	-	1.8 1.7	2.3 2.2	V
$I_{RM1}$	$V_R = 600\text{ V}$ $V_R = 600\text{ V}$	-	-	100 500	$\mu\text{A}$
$t_{rr}$ $I_{rr}$ $Q_{rr}$	$I_F = 10\text{ A}$ , $di_F/dt = 200\text{ A}/\mu\text{s}$		74 6 213	120 10 600	ns A nC
$t_{rr}$ $I_{rr}$ $Q_{rr}$	$I_F = 10\text{ A}$ , $di_F/dt = 200\text{ A}/\mu\text{s}$		120 8.8 530	200 15 1500	ns A nC
$W_{AVL}$	Avalanche Energy ( $L = 40\text{ mH}$ )	10	-	-	mJ

**Notes:**

1: Pulse: Test Pulse width = 300 $\mu\text{s}$ , Duty Cycle = 2%

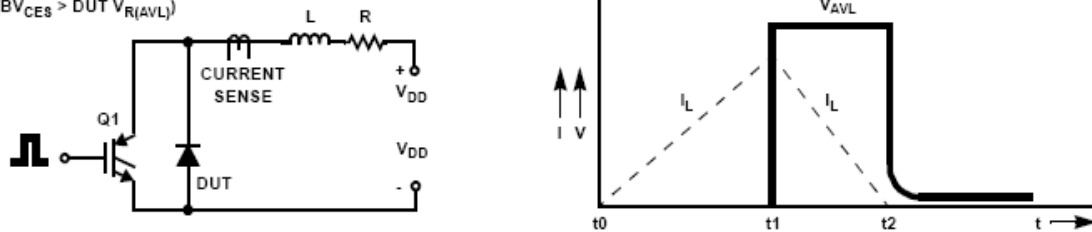
### Test Circuit and Waveforms



**Figure 1. Diode Reverse Recovery Test Circuit & Waveform**

$L = 40\text{mH}$   
 $R < 0.1\Omega$   
 $V_{DD} = 50\text{V}$

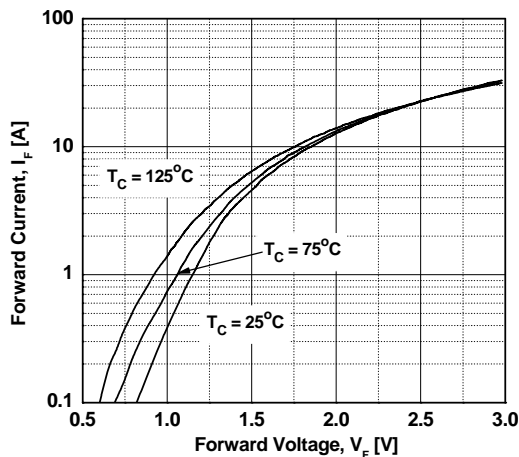
$E_{AVL} = 1/2LI^2 [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]$   
 $Q1 = \text{IGBT } (BV_{CES} > \text{DUT } V_{R(AVL)})$



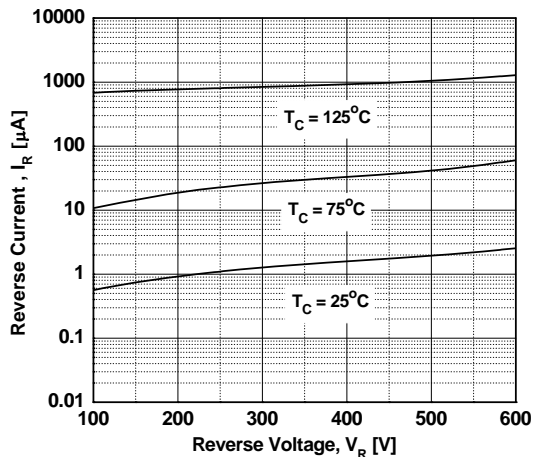
**Figure 2. Unclamped Inductive Switching Test Circuit & Waveform**

## Typical Performance Characteristics

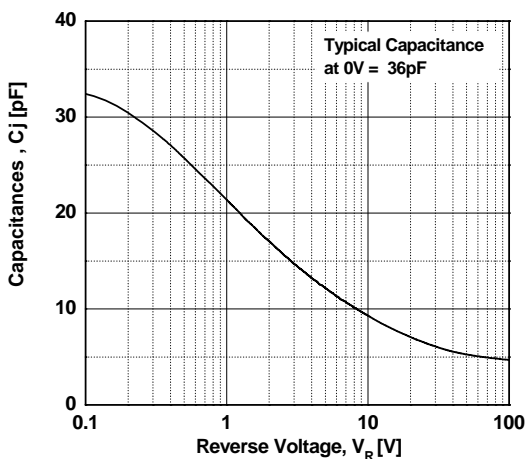
**Figure 3. Typical Forward Voltage Drop vs. Forward Current**



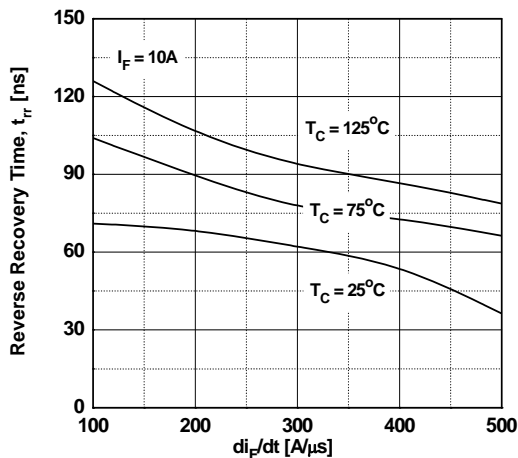
**Figure 4. Typical Reverse Current vs. Reverse Voltage**



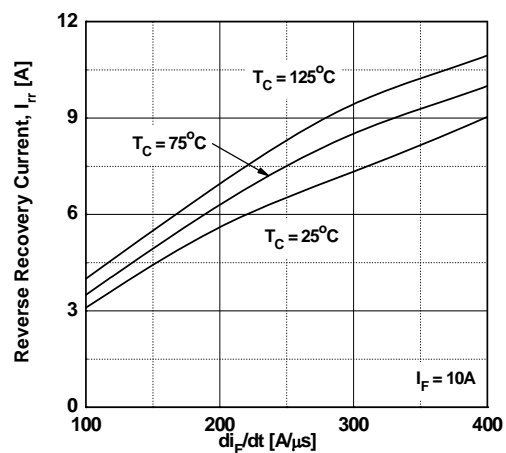
**Figure 5. Typical Junction Capacitance**



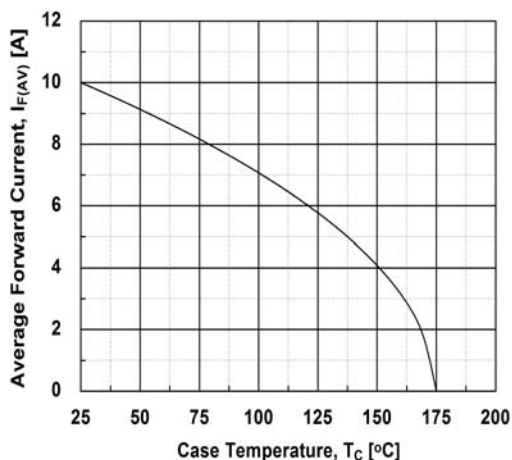
**Figure 6. Typical Reverse Recovery Time vs.  $di_F/dt$**



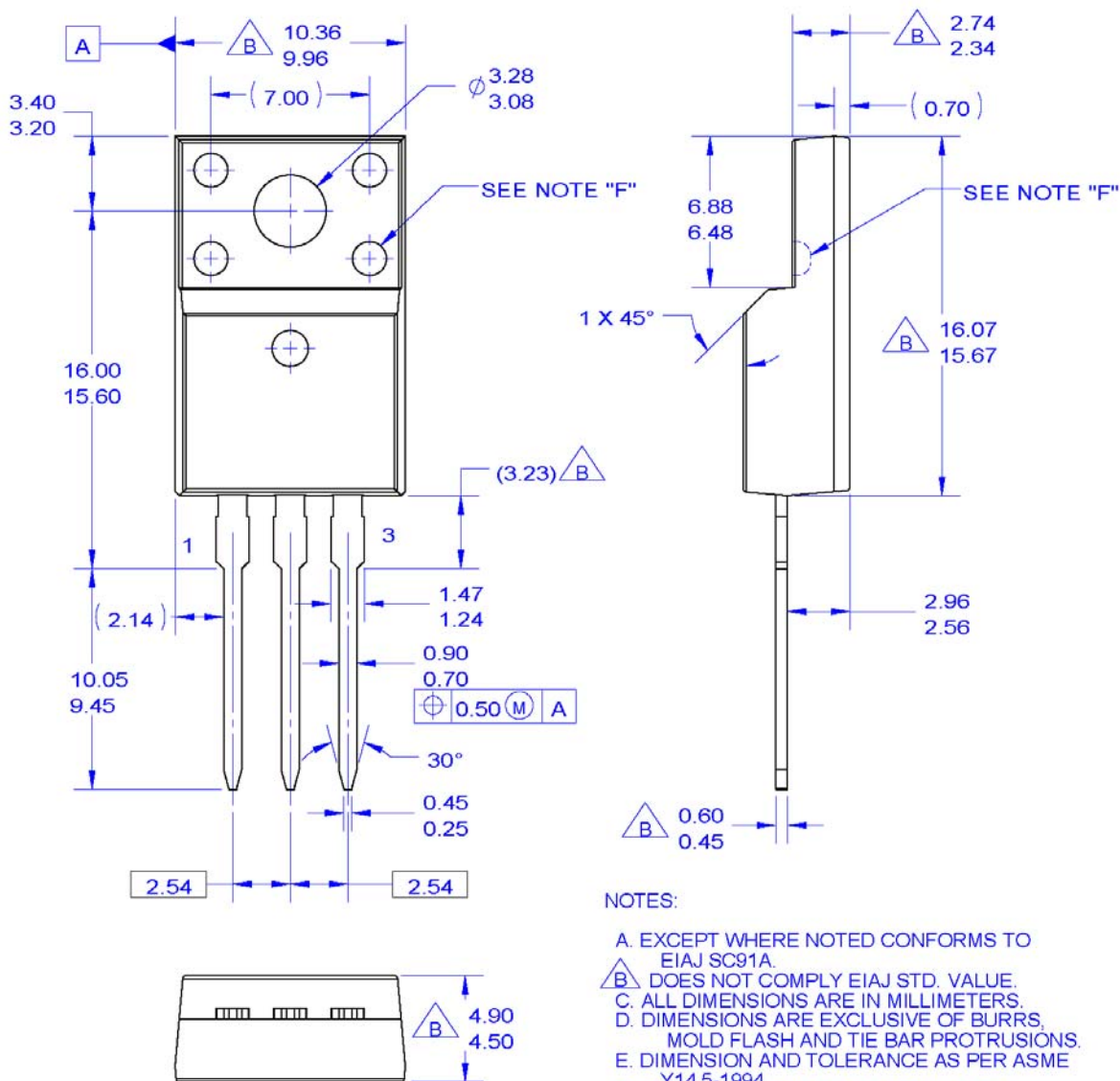
**Figure 7. Typical Reverse Recovery Current vs.  $di_F/dt$**



**Figure 8. Forward Current Derating Curve**



Package Dimensions



NOTES:

- A. EXCEPT WHERE NOTED CONFORMS TO EIAJ SC91A.
- B. DOES NOT COMPLY EIAJ STD. VALUE.
- C. ALL DIMENSIONS ARE IN MILLIMETERS.
- D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
- E. DIMENSION AND TOLERANCE AS PER ASME Y14.5-1994.
- F. OPTION 1 - WITH SUPPORT PIN HOLE.  
OPTION 2 - NO SUPPORT PIN HOLE.
- G. DRAWING FILE NAME: TO220M03REV3

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